Brobingnagian photon bunching in cathodoluminescence of excitons in WS₂ monolayer

Saskia Fiedler,† Sergii Morozov,‡ Leonid Iliushyn,§ Sergejs Boroviks,‡ Martin Thomaschewski,† Jianfang Wang,† Timothy J. Booth,‡ Nicolas Stenger,§ Christian Wolff,† and N. Asger Mortensen†,‡,§

†Center for Nano Optics, University of Southern Denmark, Campusvej 55, DK-5230 Odense M, Denmark
‡Center for Nanostructured Graphene, Technical University of Denmark, DK-2800 Kongens Lyngby, Denmark
§Department of Physics, Technical University of Denmark, DK-2800 Kongens Lyngby, Denmark

INTRODUCTION

The recent development in the synthesis and the fabrication of two-dimensional (2D) transition metal dichalcogenide (TMDC) monolayers has sparked intensive research of their implementation in applications in the emerging field of quantum information and computing technologies [1, 2]. The family of TMDC monolayers with a thickness of a few atoms provides an attractive combination of optoelectronic properties, including a direct bandgap, a strong spin-orbit coupling and splitting, an access to spin and valley degrees of freedom [3]. A TMDC monolayer is a high-quality, robust material platform for quantum light generation, where the coexistence of multiple excitons is a resource that represents an ensemble of identical quantum light sources.

Photon statistics and the second-order auto-correlation function \( g_2(\tau) \) constitute powerful indicators for the identification of single-photon sources in various solid-state platforms, while also giving insight into the quantum-mechanical correlation between emitters within an ensemble. The spontaneous emission of an individual quantum emitter results in a stream of single photons which exhibits the characteristic dip at zero delay time in the photon-correlation histogram (photon anti-bunching). In contrast, photon statistics of an ensemble formed by identical quantum emitters which can be simultaneously excited by an electron. In this article, we demonstrate large photon bunching with \( g_2(0) \) up to 156 ± 16 of a tungsten disulfide monolayer, exhibiting a strong dependence on the electron-beam current density. To further improve the excitation synchronization and the electron-emitter interaction, we show exemplary that the careful selection of a simple and compact geometry – a thin, monocristalline gold nanodisk – can be used to realize a record-high bunching \( g_2(0) \) of up to 2152 ± 236. This approach to control the electron excitation of excitons in a WS₂ monolayer allows for the synchronization of quantum emitters in an ensemble, which is important to further advance quantum information processing and computing technologies.

Figure 1. Electron-beam excitation of hBN-encapsulated WS₂ monolayer. a Schematics of the experimental setup for detection of electron-beam-induced emission from a WS₂ monolayer. The generated emission is collected with a parabolic mirror and directed towards a spectrometer and HBT interferometer. b Electron beam generates electron-hole pairs in hBN, which relax to WS₂ monolayer emitting light towards a spectrometer and HBT interferometer.
instrumentation. Therefore, to further boost the photon bunching, two requirements need to be met, (i) high-quality quantum ensembles consisting of identical and densely localized emitters within a sub-wavelength volume, and (ii) a geometry increasing the probability of electron-emitter interaction.

In this article, we study the luminescence properties and photon statistics of a tungsten disulfide (WS$_2$) monolayer encapsulated in hexagonal boron nitride (hBN) layers. Using electron-beam excitation, we demonstrate a high photon bunching of $g_2(0) = 156 \pm 16$ which is due to the naturally high quality of WS$_2$. We further explore methods for improving the excitation synchronization and electron-emitter interaction via adding a monocrystalline gold nanodisk. In such a geometry, we achieve record-high photon bunching of $g_2(0) = 2152 \pm 236$, exceeding the previously reported values by two orders of magnitude. Our simple geometry offers a robust and compact platform to generate quantum light with Brobdingnagian [9] photon bunching statistics, which has important applications in quantum information processing and computing technologies.

RESULTS AND DISCUSSION

Sample and experimental setup

We perform photoluminescence (PL) and cathodoluminescence (CL) experiments of a WS$_2$ monolayer sandwiched between two thin hBN flakes (see details in Methods). The hBN encapsulation on both sides of the WS$_2$ monolayer serves three purposes: (i) protecting the WS$_2$ from electron-beam damage and contamination, (ii) increasing the effective interaction volume of incoming electrons with the monolayer, and (iii) providing a layer for the generation of additional charge carriers which can subsequently diffuse into the WS$_2$ and radiatively recombine, thereby significantly enhancing the CL intensity [10].

Fig. 1a schematically presents the experimental setup for the electron-beam excitation of the hBN–WS$_2$–hBN sample and the collection of the generated CL. Here, the electron beam is focused onto the hBN–WS$_2$–hBN stack, and the generated CL is subsequently collimated by a parabolic mirror and focused onto a spectrometer and a Hanbury Brown and Twiss (HBT) interferometer (see Methods).

Photo and electron-beam excitation

Photo and electron-beam excitation are essentially different mechanisms of exciton generation in a WS$_2$ monolayer. An incoming photon typically creates one electron-hole pair in the WS$_2$ monolayer, while an incoming electron can excite many electron-hole pairs in the sample (Fig. 1b), predominantly in the thicker hBN layers due to a large interaction volume [11]. The latter process can be described by a scattered incoming electron which excites high-energy interband transitions in the sample, also referred to as “bulk plasmons” in electron spectroscopy literature [6, 12, 13]. They subsequently decay into multiple identical electron-hole pairs which, after the typical excitonic lifetime, exhibit synchronized radiative recombination. The photons appear to arrive as a “packet” and can be detected with the HBT interferometer as photon bunching ($g_2(0) > 1$).

In Fig. 2a, we compare spectral emission properties of the hBN–WS$_2$–hBN stack under photo- and electron-beam excitation. The PL spectrum is centered around 621 nm and has a red-shifted satellite peak at 635 nm (green line in Fig. 1c). These emission lines are characteristic for the neutral and red-shifted charged exciton (trion) in WS$_2$ monolayers at room temperature [14]. In contrast, the CL spectrum in Fig. 2a is dominated by the neutral exciton peak at 626 nm which is red-shifted with respect to the PL spectrum. In general, we observe a sub-10 nm spectral wandering of the excitonic peak in both PL and CL measurements which is possibly due to local strain within the WS$_2$ monolayer [15].

Fig. 2b presents a CL intensity map obtained by scanning the electron beam over the hBN–WS$_2$–hBN sample. The spatial CL distribution reveals areas of lower intensity, which are due to cracks in the WS$_2$ monolayer. The round dark patches apparent in the CL map can be attributed to bubbles in between the three layers, as the lack of adherence of in the stacked sample has been shown to result in quenched luminescence [16].

Fig. 2c displays a corresponding PL confocal map obtained with laser excitation at 404 nm. We find a similar intensity distribution as in the CL map in Fig. 2b, although characterized by a lower spatial resolution than with an electron beam.

The photon statistics of emission generated from the hBN–WS$_2$–hBN sample drastically depend on the type of excitation. Fig. 2c presents photon correlation histograms obtained under photo and electron-beam excitation. Electron-beam excita-

![Figure 2. Photo- and electron-beam excitation of hBN-encapsulated WS$_2$ monolayer. a PL and CL spectra of WS$_2$–hBN heterostructure. b CL intensity map obtained by electron-beam scanning of the sample. c Electron-beam excitation synchronizes emitters and leading to the photon bunching, while photo excitation is able to generate only a flat $g_2(0) = 1$. d PL confocal intensity map of the sample.](image-url)
We fit the examined dynamics with $g_2(0)$ (see SI Fig. SX). The CL spectra collected at varying $I$ show that the applied electron-beam current is limited by the instrument. Sample degradation at high electron-beam currents is observed due to the larger amount of incoming electrons, generating more electron-hole pairs in the sample, which can subsequently recombine radiatively in the WS$_2$ monolayer. The CL spectra collected at varying $I$, ranging from 3 pA to 211 pA, are shown in Fig. 3a. At higher $I$ (211 pA), the increase of the neutral exciton intensity is accompanied by the appearance of a red-shifted trion peak to 640 nm (violet line in Fig. 3a). In contrast, the amplitude of photon bunching peak follows the opposite trend; with increasing $I$, the synchronization of generated emission is decreased, resulting in a lower photon bunching amplitude in CL.

The mechanism behind the photon bunching can be attributed to the synchronization of emission from emitters, where each incoming electron creates a photon packet. With increasing electron-beam current, the electrons arrive closer in time and the photon packets become increasingly indistinguishable, thereby reducing the bunching factor until the Poissonian distribution $g_2(0, \infty) = 1$ is reached. In the hBN–WS$_2$–hBN sample, the inverse $I$-dependence is confirmed in Fig. 3c, although the Poissonian distribution cannot be reached due to sample degradation at high electron-beam currents $I > 250$ pA.

**CL response to electron-beam current**

The CL intensity and the amplitude of photon bunching in CL can be controlled by the electron-beam current $I$. As the electron-beam current is increased, a higher CL intensity is observed due to the larger amount of incoming electrons, generating more electron-hole pairs in the sample, which can subsequently recombine radiatively in the WS$_2$ monolayer. The CL spectra demonstrate the growth of CL intensity at increasing electron-beam current. Trion emission accompanies the neutral exciton at the high electron-beam current. The CL spectra do not reveal any emission effects with increasing $I$, similar to the bare hBN–WS$_2$–hBN sample. However, the CL spectra do not reveal any emission enhancement which would indicate a plasmon-assisted Purcell effect, nor any evidence of strong coupling (Fig. 4a). This observation is in agreement with the PL measurements, where the position of the Au nanodisks distributed over the entire hBN–WS$_2$–hBN sample cannot be made out. We ascribe this lack of luminescence enhancement to the large separation of 35 nm between the gold nanodisk and the WS$_2$ monolayer which does not allow for efficient near-field interaction.

A further increase of the photon bunching factor by reducing the applied electron-beam current is limited by the instrument.

**Boosting bunching through geometry**

Increasing the acceleration voltage potentially allows to reduce the current to sub-pA, however in practice, it causes severe sample charging already at 5 kV. To overcome this limit, we suggest to modify the geometry by adding a thin gold nanodisk to induce a local change of electron beam excitation. The CL spectra demonstrate the growth of CL intensity at increasing electron-beam current. Trion emission accompanies the neutral exciton at the high electron-beam current. The photon correlation histograms show reduction of photon bunching with the increase of electron-beam current. The photon bunching factor $g_2(0)$ is in inverse dependence with the electron-beam current.

Decreasing the acceleration voltage potentially allows to reduce the current to sub-pA, however in practice, it causes severe sample charging already at 5 kV. To overcome this limit, we suggest to modify the geometry by adding a thin gold nanodisk to induce a local change of electron beam excitation. The CL spectra demonstrate the growth of CL intensity at increasing electron-beam current. Trion emission accompanies the neutral exciton at the high electron-beam current. The photon correlation histograms show reduction of photon bunching with the increase of electron-beam current. The photon bunching factor $g_2(0)$ is in inverse dependence with the electron-beam current.

**Figure 3. Cathodoluminescence of hBN-encapsulated WS$_2$ monolayer at low and high electron-beam current.** a 10 kV-CL spectra demonstrate the growth of CL intensity at increasing electron-beam current. Trion emission accompanies the neutral exciton at the high electron-beam current. b Photon correlation histograms show reduction of photon bunching with the increase of electron-beam current. c Photon bunching factor $g_2(0)$ is in inverse dependence with the electron-beam current.

**Figure 3. Cathodoluminescence of hBN-encapsulated WS$_2$ monolayer at low and high electron-beam current.** a 10 kV-CL spectra demonstrate the growth of CL intensity at increasing electron-beam current. Trion emission accompanies the neutral exciton at the high electron-beam current. b Photon correlation histograms show reduction of photon bunching with the increase of electron-beam current. c Photon bunching factor $g_2(0)$ is in inverse dependence with the electron-beam current.
the photon bunching factor. The Au nanodisks themselves – on hBN only – exhibit dim CL emission (see spectrum in SI Fig. SX), which allowed us to quantify the bunching factor to $g_2(0) = 43.1 \pm 4.9$ of a similarly sized 120 nm nanodisk (orange in Fig. 4b). Fig. 4b further compares the photon correlation histograms measured at identical excitation parameters (8 pA, 30 kV) from the hBN–WS$_2$–hBN stack (blue), and a system of a 120 nm-Au nanodisk on hBN–WS$_2$–hBN-stack (dark red). The fit of the histograms provides information about the lifetime of the generated emission $\tau_0$ and the bunching factor $g_2(0)$. We observe a minor change in emission lifetime of WS$_2$ after the addition of the Au nanodisk, extracting values of $\tau_{WS_2} = 365 \pm 18$ ps and $\tau_{WS_2, Au} = 416 \pm 10$ ps. Therefore, we conclude that the addition of an Au nanodisk did not facilitate the creation of additional, faster relaxation channels for the WS$_2$-excitons which is in agreement with the absence of Purcell enhancement. For the bare Au nanodisk, however, we measure a lifetime of $\tau_{Au} = 196 \pm 34$ ps, which is close to the temporal limit of our setup (180 ps). We also extract a photon bunching factor of 105 $\pm$ 11 for the bare hBN–WS$_2$–hBN-sample, which greatly increases to 829 $\pm$ 114 for the system of the 120 nm-Au nanodisk on the hBN–WS$_2$–hBN-stack at 30 kV. A simple addition of the bare Au nanodisk and the hBN-encapsulated WS$_2$ bunching factors cannot explain the huge increase of bunching to 829 $\pm$ 114 (which we will focus on in the next section). The highest bunching factor of 2152 $\pm$ 236, we observe at the lowest electron-beam current of 3 pA (at 10 kV) for the Au nanodisk on the hBN–WS$_2$–hBN-sample (red dashed line in Fig. 3c).

Finally, we confirm the inverse electron-beam current dependence of the photon bunching using a different geometry and a reduced acceleration voltage (from 30 kV to 10 kV) to allow for a further reduction in $I$. We plot the summary of the results in Fig. 4c, including fits of the $g_2(0, I)$-data with an inverse current function (red curves). We extract from the fit a large change in $I_0$ from $I_0^{WS_2} = 477 \pm 14$ pA to $I_0^{WS_2, Au} = 5257 \pm 154$ pA, which indicates the change of probability of electrons to interact with the sample due to the presence of an Au nanodisk.

Simulations of electron trajectories

We perform Monte Carlo simulations [18] to shed light on the huge bunching enhancement of the hBN–WS$_2$–hBN-sample caused by the addition of an Au nanodisk. Fig. 4a,b present the results for electron-beam trajectory simulations of the investigated geometries for a 10 kV-electron-beam with a spot size of 5 nm. Here, the blue lines represent the primary electrons within the sample stack, while the red ones indicate back-scattered electrons (BSE). At the position of the WS$_2$ monolayer (Fig. 4c, marked as a thin green line, the spatial distribution of the primary electrons remains close to the original 5 nm-electron-beam diameter. In the case of an additional 20 nm-thin gold film on the topmost layer (cf. Fig. 4b), representing the Au nanodisk, the primary electrons are widely scattered within the sample resulting in enormous spread of the electron-beam. In fact, the divergence is so large that no clear electron-beam diameter can be assigned within the range of 50 nm which is depicted in Fig. 4d. This huge spread of the electron beam reduces the effective electron density at the position of the WS$_2$ monolayer which is equivalent to a reduced current at a given sample area. As a result, the photon bunching is greatly increased.

Ultimately, we conclude that the electron current density determines the photon bunching in CL; not only the temporal distance between incoming electrons plays a crucial role but also the number of electrons within a certain area of the sample. To verify experimentally this important finding, we mimic the spread of the electron beam at the position of the WS$_2$ monolayer by manually defocusing the electron beam. Here, we increase the working distance which effectively spreads the electron beam to larger spot sizes without changing the initial electron-beam parameters, such as acceleration voltage and current. We observe a similar trend of high photon bunching...
viously reported values. Employing Monte Carlo simulations computing information technologies. Brobdingnagian photon bunching for applications in quantum g

g(0) to extremes, which o

g(0) = 156 ± 16) from a WS

CONCLUSION AND OUTLOOK

In conclusion, we demonstrated the importance of electron-beam excitation for synchronization of large ensembles, and for achieving high photon bunching factors. We reported a high photon bunching \( g_2(0) \) from a WS

CL correlation measurements. For the CL second-order correlation measurements, i.e., the \( g_2(\tau) \) correlation function as a function of the correlation time \( \tau \) for the temporal CL intensity \( I(t) \),

\[
g_2(\tau) = \frac{\langle I(t)I(t+\tau) \rangle}{\langle I(t) \rangle^2} = \frac{\langle I(t)I(t+\tau) \rangle}{\langle I(t) \rangle^2}, \tag{1}
\]

a 90:10 beam splitter is inserted before the spectrometer to allow for concurrent spectral and correlation analysis of the sample (see Fig. 1c). 10% of the CL emission is being transmitted onto the spectrometer, while the remaining 90% is being reflected onto a Hanbury Brown and Twiss (HBT) interferometer. Here, the light beam is split by a 50:50 beam splitter, creating a time delay \( \tau \) between the incoming photons which are detected via two separated avalanche photo diodes (APD, SPCM-AQRH-14-TR, Excelitas Technologies).

We fit experimental time correlation histograms with a cur-
dependent function: [6]
\[
g_2(\tau, I) = 1 - \frac{1}{N} e^{-\tau/\tau_e} + \frac{I_0}{I} \left( 1 - \frac{1}{N} \right) e^{-\tau/\tau_e}, \tag{2}
\]
where \(N\) is an effective number of emitters in the ensemble, \(\tau_e\) is the emission lifetime, \(I_0\) is a free parameter describing the probability of the electron beam to interact with the emitters in ensemble.

**ACKNOWLEDGMENTS**

N. A. M. is a VILLUM Investigator supported by VILLUM FONDEN (Grant No. 16498). S. M. acknowledges funding from the Marie Skłodowska-Curie Action (Grant agreement No. 101032967). C. W. acknowledges funding from a MULTIPLY fellowship under the Marie Skłodowska-Curie COFUND Action (Grant agreement No. 713694). The Center for Nanostructured Graphene is sponsored by the Danish National Research Foundation (Project No. DNRF103).

* S. F. and S. M. contributed equally to this work.
† asger@mailaps.org